DSC2P01

Silicon NPN epitaxial planar type

For low frequency amplification Darlington connection

Features

- \bullet High forward current transfer ratio h_{FE} with excellent linearity
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

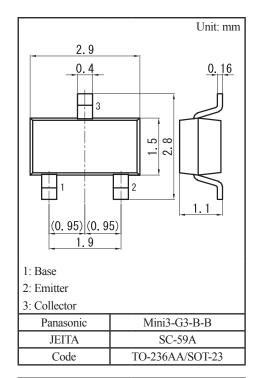
Marking Symbol: E5

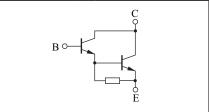
Packaging

DSC2P01×0L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	60	V
Collector-emitter voltage (Base open)	V _{CEO}	V _{CEO} 50	
Emitter-base voltage (Collector open)	V _{EBO}	5	V
Collector current	I _C	I _C 500	
Peak collector current	I _{CP}	750	mA
Total power dissipation	P _T	200	mW
Junction temperature	Tj	150	°C
Operating ambient temperature	T _{opr}	-40 to +85	°C
Storage temperature	T _{stg}	-55 to +150	°C





Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 100 \ \mu {\rm A}, I_{\rm E} = 0$	60			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	50			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 100 \ \mu A, I_{\rm C} = 0$	5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 25 \text{ V}, I_E = 0$			100	nA
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 4 V, I_C = 0$			100	nA
Forward current transfer ratio *1, 2	\mathbf{h}_{FE}	$V_{CE} = 10 \text{ V}, I_C = 500 \text{ mA}$	4000		20000	
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}$			2.5	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_{\rm C} = 500 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}$			3.0	V

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement

*2: Rank classification

Code	Q	R	
Rank	Q	R	
$h_{\rm FE}$	4000 to 10000	8000 to 20000	
Marking Symbol	E5Q	E5R	

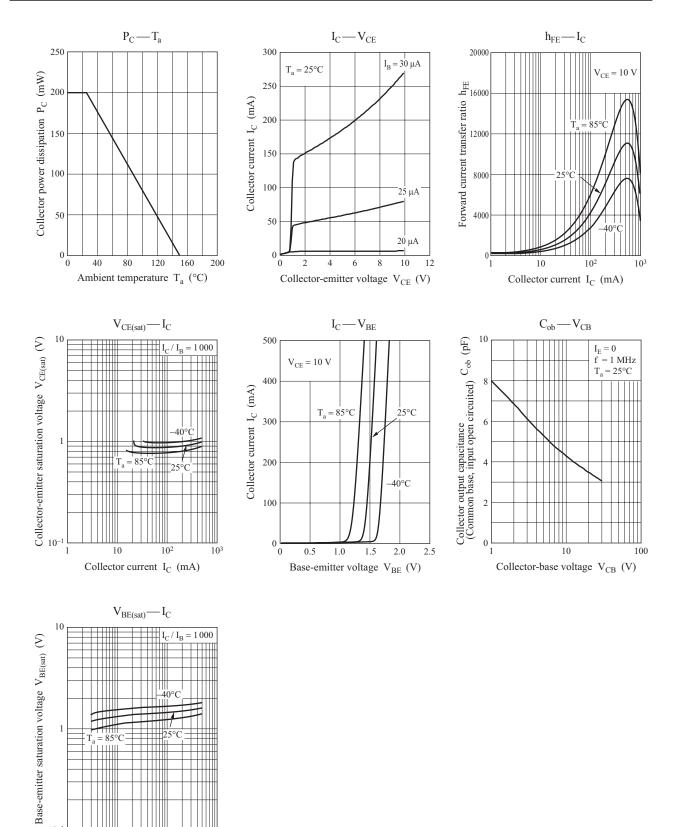
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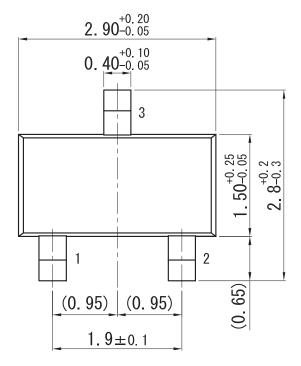
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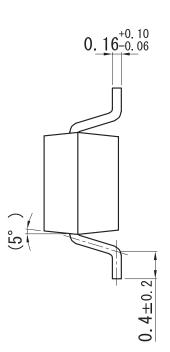
Collector current I_C (mA)

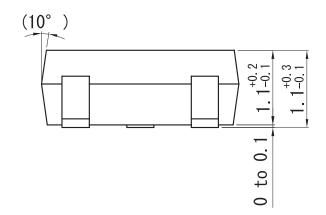


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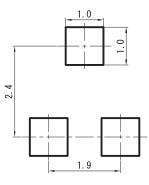
Mini3-G3-B-B







Land Pattern (Reference) (Unit: mm)



Unit: mm

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